

**R15**

Code No: 123AU

**JAWAHARLAL NEHRU TECHNOLOGICAL UNIVERSITY HYDERABAD****B. Tech II Year I Semester Examinations, November/December - 2016****ELECTRONIC DEVICES AND CIRCUITS****(Common to EEE, ECE, CSE, EIE, IT, ETM, MCT)****Time: 3 Hours****Max. Marks: 75****Note:** This question paper contains two parts A and B.

Part A is compulsory which carries 25 marks. Answer all questions in Part A.

Part B consists of 5 Units. Answer any one full question from each unit.

Each question carries 10 marks and may have a, b, c as sub questions.

**PART- A****(25 Marks)**

- 1.a) Define static and dynamic resistance of P-N diode. [2]
- b) Explain about Zener break down. [3]
- c) Define ripple factor. [2]
- d) Explain about voltage regulation. [3]
- e) What are the applications of UJT? [2]
- f) What do you mean by early effect? [3]
- g) Explain about collector feedback bias. [2]
- h) Write about thermal runaway. [3]
- i) Mention small signal parameters of JFET. [2]
- j) Differentiate between BJT and JFET. [3]

**PART-B****(50 Marks)**

- 2.a) Compare the characteristics of PN junction diode, Zener Diode and Tunnel diode.
- b) For a Ge diode, the  $I_0=2\mu\text{A}$  and the voltage of 0.26V is applied. Calculate the forward and reverse dynamic resistance values at room temperature. [5+5]

**OR**

- 3.a) Derive an expression for transition capacitance of a diode.
- b) Explain Avalanche and Zener Breakdowns. [5+5]
- 4.a) Explain the operation of Full Wave Rectifier with Induction filter with necessary diagrams.
- b) A diode whose internal resistance is  $20\Omega$  is to supply power to a  $100\Omega$  load from 110V (R.M.S) source of supply. Calculate:
  - i) Peak Load Current
  - ii) DC Load Current
  - iii) AC Load Current
  - iv) % Regulation from No load to given load. [5+5]

**OR**

- 5.a) Explain the operation of Full Wave Rectifier with necessary graphs.
- b) A  $3K\Omega$  resistive load is to be supplied with a D.C. voltage of 300V from A.C. voltage of adequate magnitude and 50Hz frequency by wave rectification. The LC filter is used along the rectifier. Design the bleeder resistance, turns ratio of transformer, VA rating of transformer and PIV rating of diodes. [5+5]

- 6.a) Derive Emitter Efficiency, Transport factor and large signal current gain and derive the relation between them.  
b) Explain how transistor works as an amplifier? [5+5]

**OR**

- 7.a) Explain the operation of CC Configuration of BJT and its input and output characteristics briefly.  
b) Explain about Punch through and Base width modulation. [5+5]

- 8.a) What is Biasing? Explain the need of it. List out different types of biasing methods.

- b) In a Silicon transistor circuit with a fixed bias,  
 $V_{CC}=9V$ ,  $R_C=3K\Omega$ ,  $R_B=8K\Omega$ ,  $\beta=50$ ,  $V_{BE}=0.7V$ .  
Find the operating point and Stability factor. [5+5]

**OR**

- 9.a) Derive the expression for stability factor of self bias circuit.  
b) Explain in detail about Thermal Runaway and Thermal Resistance. [5+5]

- 10.a) Why we call FET as a Voltage Controlled Device.

- b) For the Common Source Amplifier, calculate the value of the voltage gain, given  
i)  $r_d=100K\Omega$ ,  $R_L=10K\Omega$ ,  $g_m=300\mu$  and  $R_O=9.09K\Omega$ .  
ii) If  $C_{DS}=3pF$ , determine the output impedance at a signal frequency of 1 MHz. [5+5]

**OR**

- 11.a) Define DC Drain resistance, AC Drain Resistance, Amplification Factor and derive them.  
b) What are the values of  $I_D$  and  $g_m$  for  $V_{GS} = -0.8V$  if  $I_{DSS}$  and  $V_P$  are given as 12.4mA and -6V respectively? [5+5]

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